阅读申明

1.本站收集的数据手册和产品资料都来自互联网，版权归原作者所有。如读者和版权方有任何异议请及时告之，我们将妥善解决。
2.本站提供的中文数据手册是英文数据手册的中文翻译，其目的是协助用户阅读，该译文无法自动跟随原稿更新，同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
3.本站提供的产品资料，来自厂商的技术支持或者使用者的心得体会等，其内容可能存在描叙上的差异，建议读者做出适当判断。
4.如需与我们联系，请发邮件到marketing@iczoom.com，主题请标有"数据手册"字样。

Read Statement

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.

2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.

3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.

4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

DS1135L
3V 3-in-1 High-Speed Silicon Delay Line

FEATURES

- **All-Silicon Timing Circuit**
- **Three Independent Buffered Delays**
- **Stable and Precise Over Temperature and Voltage**
- **Leading and Trailing Edge Precision Preserves the Input Symmetry**
- **Vapor Phase and IR Reflow Solderable**
- **Available in Tape and Reel**
- **Delays Specified Over Both Commercial and Industrial Temperature Ranges**
- **3V Operation**
- **Recommended Replacement for DS1033**

PIN ASSIGNMENT

IN1	1	8	V_{CC}
IN2	2	7	OUT1
IN3	3	6	OUT2
GND	4	5	OUT3
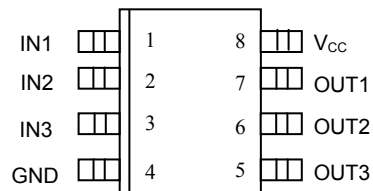
DS1135LZ 8-Pin SO (150 mils)

PIN DESCRIPTION

| IN1-IN3 | - Input Signals |
OUT1-OUT3	- Output Signals
V_{CC}	- +3V Supply
GND	- Ground

DESCRIPTION

The DS1135L series is a low-power, 3V high-speed version of the popular DS1013, DS1033, and DS1035 series.

The DS1135L series of delay lines have three independent logic buffered delays in a single package. The device is our fastest 3-in-1 delay line. It is available in a 150-mil 8-pin SO.

The device features precise leading and trailing edge accuracy. It has the inherent reliability of an all-silicon delay line solution.

Standard delay values are indicated in Table 1.

LOGIC DIAGRAM Figure 1

IN ──▷○─── [TIME DELAY] ───▷○─── OUT

ONE OF THREE
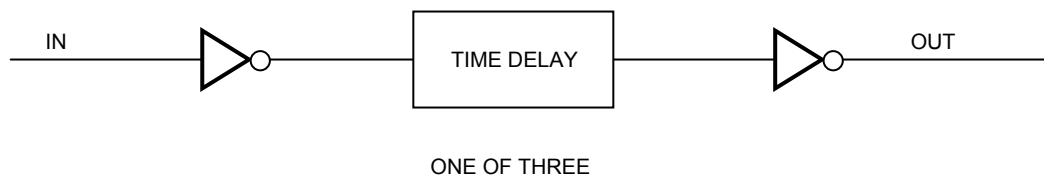
PART NUMBER DELAY TABLE (t_{PLH}, t_{PHL}) Table 1

PART NUMBER	DELAY PER OUTPUT (ns)	INITIAL TOLERANCE (Note 1)	TOLERANCE OVER TEMP AND VOLTAGE (Note 2)	
			0°C to +70°C	-40°C to +85°C
DS1135LZ-10+	10/10/10	±1.0ns	±2.0ns	±3.0ns
DS1135LZ-12+	12/12/12	±1.0ns	±2.0ns	±3.0ns
DS1135LZ-15+	15/15/15	±1.0ns	±2.5ns	±4.0ns
DS1135LZ-20+	20/20/20	±1.0ns	±2.5ns	±4.0ns
DS1135LZ-25+	25/25/25	±1.5ns	±3.0ns	±5.0ns
DS1135LZ-30+	30/30/30	±1.5ns	±3.0ns	±5.0ns

*+Denotes a lead(Pb)-free/RoHS-compliant package.*

NOTES:
1. Nominal conditions are +25°C and V_{CC} = +3.3V.
2. Voltage range of 2.7V to 3.6V.
3. Delay accuracies are for both leading and trailing edges.

TEST SETUP DESCRIPTION
Figure 2 illustrates the hardware configuration used for measuring the timing parameters of the DS1135L. The input waveform is produced by a precision pulse generator under software control. Time delays are measured by a time interval counter (20 ps resolution) connected to the output. The DS1135L output taps are selected and connected to the interval counter by a VHF switch control unit. All measurements are fully automated with each instrument controlled by the computer over an IEEE 488 bus.

DS1135L TEST CIRCUIT Figure 2
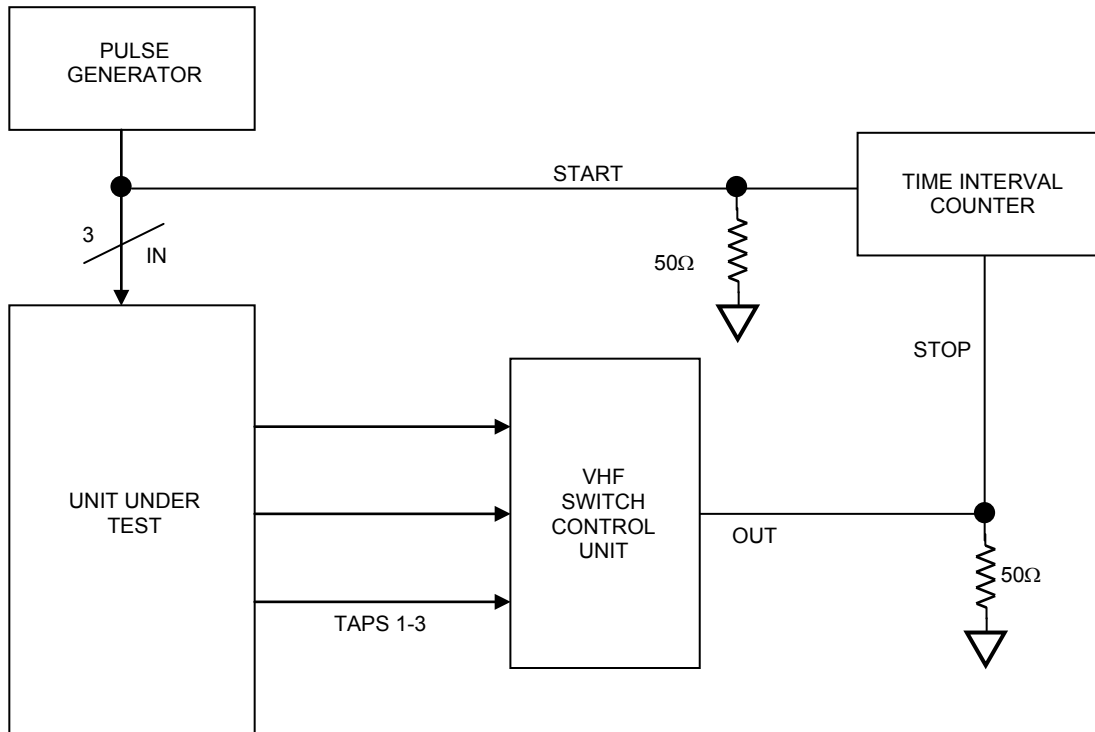
ABSOLUTE MAXIMUM RATINGS

Voltage Range on Any Pin Relative to Ground	-1.0V to +6.0 V
Short-Circuit Output Current	50mA for 1 second
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-55°C to +125°C
Lead Temperature (soldering, 10 seconds)	+300°C
Soldering Temperature (reflow)	+260°C

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.7V to 3.6V, T_A = -40°C to +85°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{CC}		2.7	3.3	3.6	V
Active Current	I_{CC}	V_{CC} = 3.6V, period = 1μs			10	mA
High Level Input Voltage	V_{IH}		2.0		V_{CC} + 0.5	V
Low Level Input Voltage	V_{IL}		-0.5		0.8	V
Input Leakage	I_L	$0V \leq V_I \leq V_{CC}$	-1.0		+1.0	μA
High Level Output Current	I_{CC}	V_{CC} = 2.7V, V_{OH} = 2V			-1.0	mA
Low Level Output Current	I_{CC}	V_{CC} = 2.7V, V_{OL} = 0.4V	8			mA

AC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.7V to 3.6V, T_A = -40°C to +85°C, unless otherwise noted.)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Period	t_{PERIOD}	2 (t_{WI})			ns	
Input Pulse Width	t_{WI}	100% of Delay Value			ns	
Input-to-Output Delay	t_{PLH}, t_{PHL}	See Table 1			ns	
Output Rise or Fall Time	t_{OF}, t_{OR}		2.0	2.5	ns	
Power-up Time	t_{PU}			1	ms	2

CAPACITANCE

(T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	C_{IN}			10	pF	

TEST CONDITIONS

Ambient Temperature: 25°C ± 3°C
Supply Voltage (V_{CC}): 3.3V ± 0.1V
Input Pulse:
        High: 3.0V ± 0.1V
        Low: 0.0V ± 0.1V
Source Impedance: 50Ω Max.
Rise and Fall Time: 3.0ns Max. — Measured between 0.6V and 2.4V.
Pulse Width: 500ns
Pulse Period: 1µs
Output Load Capacitance: 15pF
Output: Each output is loaded with the equivalent of one 74F04 input gate.
        Data is measured at the 1.5V level on the rising and falling edges.

Note: The above conditions are for test only and do not restrict the devices under other data sheet conditions.

NOTES:

1. All voltages are referenced to ground.
2. Power-up time is the time from the application of power to the time stable delays are being produced at the output.

TIMING DIAGRAM
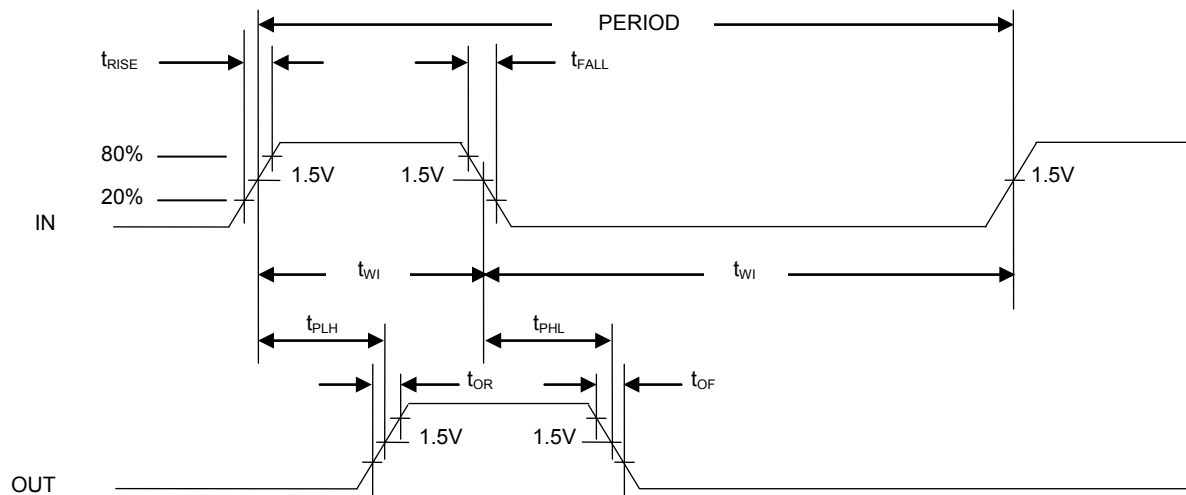
TERMINOLOGY

Period: The time elapsed between the leading edge of the first pulse and the leading edge of the following pulse.

t_{WI}(Pulse Width): The elapsed time on the pulse between the 1.5V point on the leading edge and the 1.5V point on the trailing edge or the 1.5V point on the trailing edge and the 1.5V point on the leading edge.
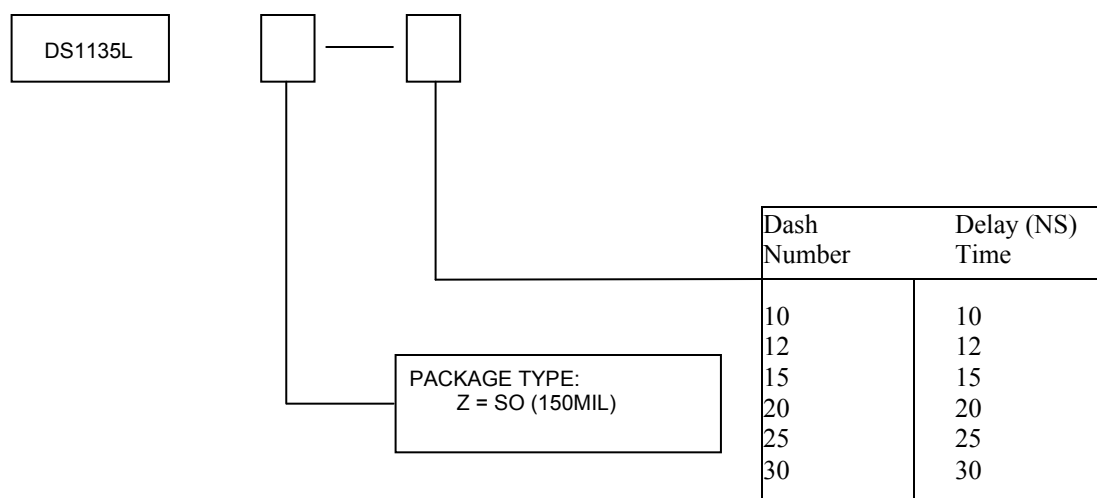
t_{RISE} (Input Rise Time): The elapsed time between the 20% and the 80% point on the leading edge of the input pulse.

t_{FALL} (Input Fall Time): The elapsed time between the 80% and the 20% point on the trailing edge on the input pulse.

t_{PLH} (Time Delay, Rising): The elapsed time between the 1.5V point on the leading edge of the input pulse and the 1.5V point on the leading edge of the output pulse.

t_{PHL} (Time Delay, Falling): The elapsed time between the 1.5V point on the falling edge of the input pulse and the 1.5V point on the falling edge of the output pulse.

ORDERING INFORMATION

DS1135L

PACKAGE TYPE:
Z = SO (150MIL)

Dash Number	Delay (NS) Time
10	10
12	12
15	15
20	20
25	25
30	30

PACKAGE INFORMATION

For the latest package outline information and land patterns (footprints), go to **www.maximintegrated.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
8 SO	S8+2	**21-0041**	**90-0096**

REVISION HISTORY

REVISION DATE	DESCRIPTION	PAGES CHANGED
8/12	Removed the μSOP package; updated the *Absolute Maximum Ratings section*; added the *Package Information* section	1, 2, 4, 6

Maxim Integrated 160 Rio Robles, San Jose, CA 95134 USA 1-408-601-1000